

# 127, 17 27, 17 (20) 77, 17 (20









## جامعة عين شمس

التوثيق الالكتروني والميكروفيلم



نقسم بللله العظيم أن المادة التي تم توثيقها وتسجيلها علي هذه الأفلام قد اعدت دون آية تغيرات



### يجب أن

تحفظ هذه الأفلام بعيداً عن الغبار

في درجة حرارة من 15-20 مئوية ورطوبة نسبية من 20-40 %

To be kept away from dust in dry cool place of 15 – 25c and relative humidity 20-40 %



ثبكة المعلومات الجامعية





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South Valley University Faculty of Science (Aswan)

#### CRYSTAL GROWTH AND STUDIES OF SOME TERNARY SEMICONDUCTOR COMPOUNDS

#### A THESIS

Submitted to the Faculty of Science (ASWAN)

South Valley University

In Partial Fulfillment of the requirements

For the Degree of Master of Science

(PHYSICS)

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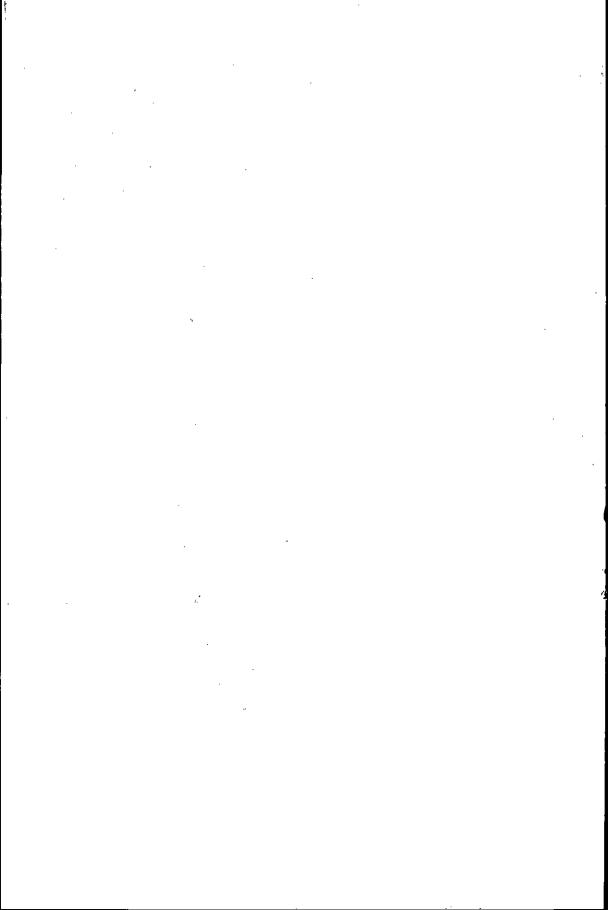
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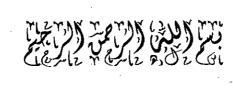
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(سورة العلق)

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## CHAPTER (1)

Introduction